PCN Number:		2022120	207002.2					te:	December 09, 2022		
Titl	e:	Qualifica	ation of TI	Malaysia as an additional Assembly and test site for select devices							
Cus	stomer	Contact		PCN	<u>l Manager</u>		Dep	pt:		Quality Services	
Proposed 1 st Ship Date:				1 IIIn / /II/3			Sample Requests accepted until:			Jan 9, 2023*	
*Sa	ımple ı	requests	received	afte	r Jan 9, 2023 will	not be	sup	port	ed.		
Change Type:											
\boxtimes	Assem	bly Site			Assembly Process				Assembly Materials		
	Desigr	1			Electrical Specification				Mechanical Specification		
\boxtimes	Test S	Site		\boxtimes	□ Packing/Shipping/Labeling				Test Process		
	Wafer	Bump Sit	e		Wafer Bump Mate	erial Waf			Wafer	Vafer Bump Process	
☐ Wafer Fab Site			☐ Wafer Fab Materials					Wafer	Fab Process		
					☐ Part number change						
	PCN Details										
Des	scriptio	n of Cha	nge:								
1											

Texas Instruments is pleased to announce the qualification of TI Malaysia as an additional Assembly and test site. Construction differences are as follows:

	Current Device Symbolization	New Device Symbolization
**ECAT	Include Value	Remove
TI Bug	Include	Replace with "TI" text
Exa mple	MUX508Q 49TG4 C2TX	MUX508Q TD 19 C2TX

Test coverage, insertions, conditions will remain consistent with current testing and verified with test MQ

Reason for Change:			
Supply continuity			
Anticipated impact on Fo	rm, Fit, Function, Quality	or Reliability (positive / negative):	
None			

Impact on Environmental Ratings

Checked boxes indicate the status of environmental ratings following implementation of this change. If below boxes are checked, there are no changes to the associated environmental ratings.

RoHS	REACH	Green Status	IEC 62474	
No Change	No Change ■ No Change ■ No Change No Change ■ No Change No	☑ No Change	⊠ No Change	

Changes to product identification resulting from this PCN:

Assembly Site	Assembly Site Origin (22L)	Assembly Country Code (23L)	Assembly City		
TAI	TAI	TWN	Chung Ho, New Taipei City		
MLA	MLA	MYS	Kuala Lumpur		

Sample product shipping label (not actual product label)

TEXAS INSTRUMENTS MADE IN: Malaysia 2DC: 20;

MSL 2 /260C/1 YEAR SEAL DT MSL 1 /235C/UNLIM 03/29/04

OPT: LBL: 5A (L)T0:1750



(1P) \$N74L\$07N\$R (Q) 2000 (D) 0336 (31T)LOT: 3959047MLA (4W) TKY(1T) 7523483812 (P) (2P) REV: (V) 0033317 (20L) CS015NE (21L) CC018A

(201) CSO: SHE (211) CCO: USA (221) ASO: MLA (231) ACO: MYS

Product Affected:

UCC23313BQDWYQ1	UCC23313QDWYRQ1	UCC23513BQDWYQ1	UCC23513QDWYQ1
UCC23313BQDWYRQ1	UCC23511QDWYQ1	UCC23513BQDWYRQ1	UCC23513QDWYRQ1
UCC23313QDWYQ1	UCC23511QDWYRQ1		

Automotive New Product Qualification Summary (As per AEC-Q100 and JEDEC Guidelines)

Optotron Automotive DWY Offload from TAI to MLA Approve Date 28-NOVEMBER-2022

Product Attributes

Attributes	Qual Device:	Qual Device:	QBS Reference:	QBS Reference:
Attributes	UCC23513QDWYRQ1	UCC23513BQDWYRQ1	<u>UCC23513QDWYQ1</u>	ISO6741QDWQ1
Automotive Grade Level	Grade 1	Grade 1	Grade 1	Grade 1
Operating Temp Range (C)	-40 to 125	-40 to 125	-40 to 125	-40 to 125
Product Function	Power Management	Power Management	Power Management	Interface
Wafer Fab Supplier	RFAB, RFAB	RFAB, RFAB	RFAB, RFAB	MH8, MH8
Assembly Site	MLA	MLA	TAI	MLA
Package Group	SOIC	SOIC	SOIC	SOIC
Package Designator	DWY	DWY	DWY	DW
Pin Count	6	6	6	16

- QBS: Qual By Similarity

- Qual Device UCC23513QDWYRQ1 is qualified at MSL2 260C
 Qual Device UCC23513BQDWYRQ1 is qualified at MSL2 260C
 Qual Device UCC23513DWYR is qualified at MSL2 260C
- Qual Device UCC23513BDWYR is qualified at MSL2 260C

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	#	Test Spec	Min Lot Qty	SS / Lot	Test Name	Condition	Duration	Qual Device: UCC23513QDWYRQ1	Qual Device: UCC23513BQDWYRQ1	QBS Reference: UCC23513QDWYQ1	QBS Reference: ISO6741QDWQ1
Test Group	A - Acce	lerated Enviror	ment St	ress Tes	its		<u> </u>				
PC	A1	JEDEC J- STD-020 JESD22- A113	3	77	Preconditioning	MSL2 260C	1 Step	No Fails	-	No Fails	No Fails
HAST	A2	JEDEC JESD22- A110	3	77	Biased HAST	130C/85%RH	96 Hours	3/231/0	-	3/231/0	3/231/0
AC/UHAST	A3	JEDEC JESD22- A102/JEDEC JESD22- A118	3	77	Autoclave	121C/15psig	96 Hours	3/231/0	-	3/231/0	3/231/0
тс	A4	JEDEC JESD22- A104 and Appendix 3	3	77	Temperature Cycle	-65C/150C	500 Cycles	3/231/0	-	3/231/0	3/231/0
HTSL	A6	JEDEC JESD22- A103	1	45	High Temperature Storage Life	150C	1000 Hours	3/231/0	-	-	3/135/0
HTSL	A6	JEDEC JESD22- A103	1	45	High Temperature Storage Life	175C	500 Hours	-	-	3/135/0	-
Test Group	B - Acce	elerated Lifetime	e Simula	tion Tes	ts						
HTOL	B1	JEDEC JESD22- A108	1	77	Life Test	125C	1000 Hours	-	-	3/231/0	3/231/0
ELFR	B2	AEC Q100- 008	1	77	Early Life Failure Rate	125C	48 Hours	-	-	3/2400/0	-
Test Group	C - Pacl	age Assembly	Integrity	Tests							
WBS	C1	AEC Q100- 001	1	30	Wire Bond Shear	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	3/90/0	1/30/0	3/90/0	3/90/0
WBP	C2	MIL-STD883 Method 2011	1	30	Wire Bond Pull	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	3/90/0	1/30/0	3/90/0	3/90/0

SD	C3	JEDEC JESD22- B102	1	15	PB Solderability	>95% Lead Coverage	-	-	-	1/15/0	1/15/0
SD	C3	JEDEC JESD22- B102	1	15	PB-Free Solderability	>95% Lead Coverage	-	-	-	1/15/0	1/15/0
PD	C4	JEDEC JESD22- B100 and B108	1	10	Physical Dimensions	Cpk>1.67	-	3/30/0	1/10/0	3/30/0	3/30/0
Test Group	D - Die F	abrication Relia	ability Te	sts							
EM	D1	JESD61	-	-	Electromigration	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
TDDB	D2	JESD35	-	-	Time Dependent Dielectric Breakdown	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
HCI	D3	JESD60 & 28	-	-	Hot Carrier Injection	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
NBTI	D4	-	-	-	Negative Bias Temperature Instability	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
SM	D5	-	-	-	Stress Migration	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
Test Group	E - Elect	rical Verificatio	n Tests								
ESD	E2	AEC Q100- 002	1	3	ESD HBM	-	2000 Volts	-	-	1/3/0	1/3/0
ESD	E3	AEC Q100- 011	1	3	ESD CDM	-	500 Volts	-	-	1/3/0	1/3/0
LU	E4	AEC Q100- 004	1	6	Latch-Up	Per AEC Q100-004	-	-	-	1/6/0	1/6/0
ED	E5	AEC Q100- 009	3	30	Electrical Distributions	Cpk>1.67 Room, hot, and cold	-	1/30/0	1/30/0	3/90/0	3/90/0
Additional T	Additional Tests										
			9.6im								
Туре	#	Test Spec	Min Lot Qty	SS / Lot	Test Name	Condition	Duration	Qual Device	Qual Device	QBS Reference	QBS Reference

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
- The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
- The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours
- The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles

Ambient Operating Temperature by Automotive Grade Level:

- Grade 0 (or E): -40C to +150C
- Grade 1 (or Q): -40C to +125C
- Grade 2 (or T): -40C to +105C
- Grade 3 (or I) : -40C to +85C

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):

- Room/Hot/Cold : HTOL, ED
- Room/Hot : THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU
- Room : AC/uHAST

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

TI Qualification ID: R-CHG-2108-033

For questions regarding this notice, e-mails can be sent to the contacts shown below or your local Field Sales Representative.

Location	E-Mail				
WW Change Management Team	PCN www admin_team@list.ti.com				

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